General Description

The MAX4295/MAX4297 mono/stereo, switch-mode (Class-D) audio power amplifiers operate from a single +2.7V to +5.5V supply. They have >85% efficiency and are capable of delivering 2W continuous power to a 4 Ω load, making them ideal for portable multimedia and general-purpose high-power audio applications.

The MAX4295/MAX4297 feature a total harmonic distortion plus noise (THD+N) of 0.4% (f_{OSC} = 125kHz), low quiescent current of 2.8mA (MAX4295) or 4.6mA (MAX4297), high efficiency, and clickless power-up and shutdown. The SHDN input disables the device and limits supply current to <1.5µA (MAX4295) or <2.3µA (MAX4297). Other features include a 1A current limit, thermal protection, and under-voltage lockout.

The MAX4295 (mono) and MAX4297 (stereo) reduce the number of required external components. Both devices have internal high-speed power-MOS transistors, allowing operation as bridge-tied load (BTL) amplifiers. The BTL configuration eliminates the need for isolation capacitors on the output. The frequency-selectable pulse-width modulator (PWM) allows the user to optimize the size and cost of the output filter.

The MAX4295 is offered in a space-saving 16-pin QSOP package, and the MAX4297 is offered in a compact 24-pin SSOP package.

_Applications

Palmtop/Notebook	Boom Boxes
Computers	AC Amplifiers
PDA Audio	Battery-Powered Speakers
Sound Cards	Cordless Phones
Game Cards	Portable Equipment

Features

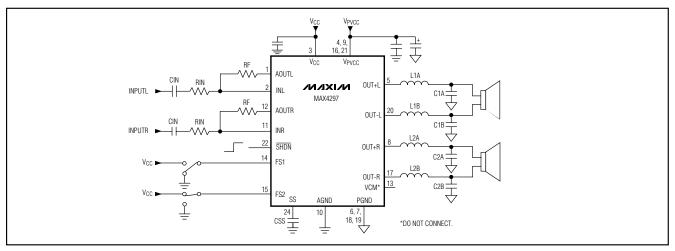
- +2.7V to +5.5V Single-Supply Operation
- 2W/Channel Output Power at 5V 0.7W/Channel Output Power at 3V
- ♦ 87% Efficiency (R_L = 4Ω, P_O = 2W, MAX4295)
- ♦ 0.4% THD+N (R_L = 4Ω, fosc = 125kHz)
- Logic-Programmable PWM Frequency Selection (125kHz, 250kHz, 500kHz, 1MHz)
- Low-Power Shutdown Mode
- ♦ Clickless Transitions Into and Out of Shutdown
- ♦ 1A Current Limit and Thermal Protection
- Available in Space-Saving Packages 16-Pin QSOP (MAX4295) 24-Pin SSOP (MAX4297)

Ordering Information

	-	-
PART	TEMP. RANGE	PIN-PACKAGE
MAX4295EEE	-40°C to +85°C	16 QSOP
MAX4295ESE	-40°C to +85°C	16 Narrow SO
MAX4297EAG	-40°C to +85°C	24 SSOP
MAX4297EWG	-40°C to +85°C	24 Wide SO

Pin Configurations appear at end of data sheet.

Typical Operating Circuit



M/IXI/M

Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

V _{CC} , PV _{CC} to GND or PGND0.3V to +6V PGND to GND±0.3V	Continuous Power Dissipation (T _A = +70°C) 16-Pin QSOP (derate 8.30mW/°C above +70°C)667mW
PV_{CC} to V_{CC} ±0.3V	24-Pin SSOP (derate 9.50mW/°C above +70°C)762mW
VCM, SS, AOUT_, IN0.3V to (V _{CC} + 0.3V)	16-Pin Narrow SO
SHDN, FS1, FS20.3V to +6V	(derate 9.52mW/°C above +70°C)696mW
OUT0.3V to (PV _{CC} + 0.3V)	24-Pin Wide SO
Op Amp Output Short-Circuit	(derate 11.76mW/°C above +70°C)941mW
Duration (AOUT_)Indefinite Short Circuit to Either Supply	Operating Temperature Range
H-Bridge Short-Circuit	MAX4295E/MAX4297E40°C to +85°C
Duration (OUT)Continuous Short Circuit to PGND,	Junction Temperature+150°C
PV _{CC} or between OUT+_ & OUT	Storage Temperature Range65°C to +150°C Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = PV_{CC} = +5V, \overline{SHDN} = V_{CC}, FS1 = GND, FS2 = V_{CC} (f_{OSC} = 250kHz)$, input amplifier gain = -1V/V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are T_A = +25°C.) (Note 1)

PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
GENERAL						
Supply Voltage Range	(Note 2)		2.7		5.5	V
Quisseent Supply Current	Output load not	MAX4295		2.8	4	mA
Quiescent Supply Current	connected	MAX4297		4.6	8	
Shutdown Supply Current	SHDN = GND	MAX4295		1.5	8	μA
		MAX4297		2.5	15	
Voltage at VCM Pin			0.285 ×	$0.3 \times$	0.315 ×	V
Voltage at VOINT III			V _{CC}	VCC	VCC	v
	FS1 = GND, FS2 = GN	1D	105	125	145	
PWM Frequency	FS1 = GND, FS2 = V _C	С	210	250	290	kHz
r www.rrequency	$FS1 = V_{CC}, FS2 = GN$	D	420	500	580	KLIZ
	$FS1 = V_{CC}, FS2 = V_{CC}$		840	1000	1160	
PWM Frequency Change with V _{CC}	$V_{CC} = 2.7V$ to 5.5V			±1	±3	kHz/V
	$V_{IN} = 0.06 \times V_{CC}$		10.2	12	13.8	
Duty Cycle	$V_{IN} = 0.30 \times V_{CC}$		49.2	50	50.8	%
	$V_{IN} = 0.54 \times V_{CC}$		86.2	88	89.8	
Duty Cycle Change with V _{CC}	$V_{IN} = 0.3 \times V_{CC}, V_{CC}$	$V_{IN} = 0.3 \times V_{CC}, V_{CC} = 2.7V$ to 5.5V		±0.02	±0.15	%/V
Switch On-Resistance	lour = 160 mA	$V_{CC} = 5V$		0.25	0.5	Ω
(each power device)			0.35	1.0	52	
H-Bridge Output Leakage	SHDN = GND			0	±5	μΑ
H-Bridge Current Limit				1		А
Soft-Start Capacitor Charging Current	V _{SS} = 0		0.75	1.35	1.95	μA
Undervoltage Lockout			1.8	2.2	2.6	V
Thermal Shutdown Trip Point				145		°C

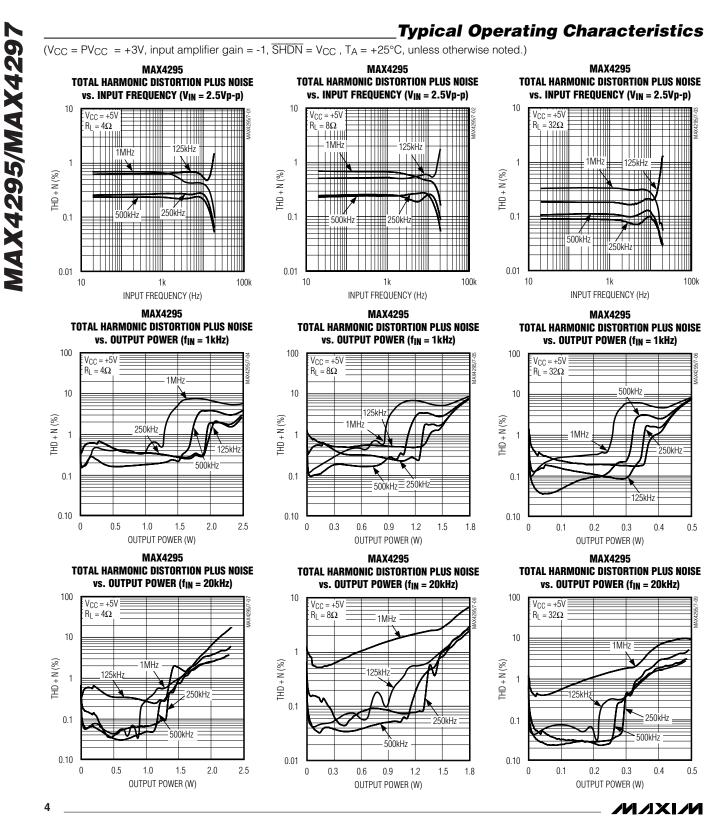
ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = PV_{CC} = +5V, \overline{SHDN} = V_{CC}, FS1 = GND, FS2 = V_{CC} (f_{OSC} = 250 \text{kHz})$, input amplifier gain = -1V/V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are T_A = +25°C.)

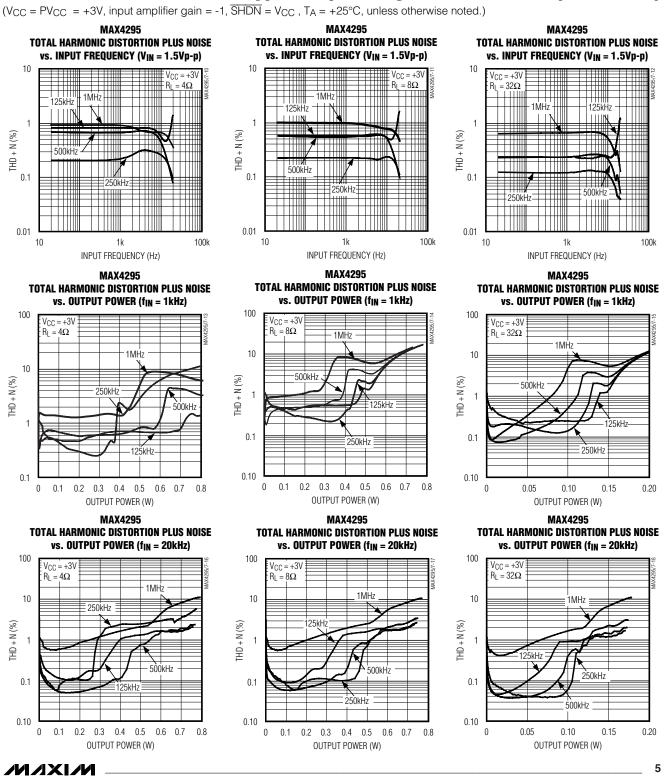
PARAMETER	CONDITIONS			ΤΥΡ	MAX	UNITS	
Input Voltage Range				0 to 0.6 x V _{CC}		V	
	$V_{CC} = +3V$, $f_{IN} = 1kHz$	$R_L = 8\Omega$		0.4			
	VCC = +3V, $IIN = IKHZ$	$R_L = 4\Omega$		0.7		- W	
Maximum Output Power	$V_{CC} = +5V$, $f_{IN} = 1kHz$	$R_L = 8\Omega$		1.2			
		$R_{L} = 4\Omega$		2			
THD Plus Noise	$R_L = 4\Omega$, $f_{IN} = 1$ kHz, $P_O =$	1W, $f_{OSC} = 125 \text{kHz}$		0.4		%	
Efficiency	MAX4295, $R_L = 4\Omega$, $f_{IN} = 1$	IkHz, P _O = 2W		87		%	
Channel Isolation	MAX4297, f _{IN} = 1kHz, PO =	= 2W		45		dB	
LOGIC INPUTS (SHDN, FS1, FS	52)						
Logic Input Current	$V_{LOGIC} = 0$ to V_{CC}			1	100	nA	
Logic Input High Voltage			0.7 × V _{CC}			V	
Logic Input Low Voltage					0.3× V _{CC}	V	
INPUT AMPLIFIER	•						
Input Offset Voltage				±0.5	±4	mV	
VOS Temp Coefficient				±5		µV/°C	
Input Bias Current	(Note 3)			±0.05	±25	nA	
Input Noise Voltage Density	f = 10kHz			32		nV/√Hz	
Input Capacitance				2.5		pF	
Output Resistance	1			0.01		Ω	
AOUT Disabled Mode Leakage Current	$\overline{SHDN} = GND, V_{AOUT} = 0$ to V_{CC}			±0.1	±1	μA	
	AOUT to GND			8			
Short-Circuit Current	AOUT to V _{CC}			65		mA	
Large-Signal Voltage Gain	$V_{OUT} = 0.2V$ to 4.6V, $R_{L(OPAMP)} = 10k\Omega$		78	115		dB	
	$V_{\text{DIFF}} \ge 10 \text{mV},$ $R_{L(\text{OPAMP})} = 10 \text{k}\Omega$	V _{CC} - V _{OH}		40	250	mV	
AOUT Voltage Swing		V _{OL}		40	100		
Gain Bandwidth Product		1		1.25		MHz	
Power-Supply Rejection	V _{CC} = +2.7V to +5.5V		66	90		dB	
Maximum Capacitive Load	No sustained oscillations		ľ	200		рF	

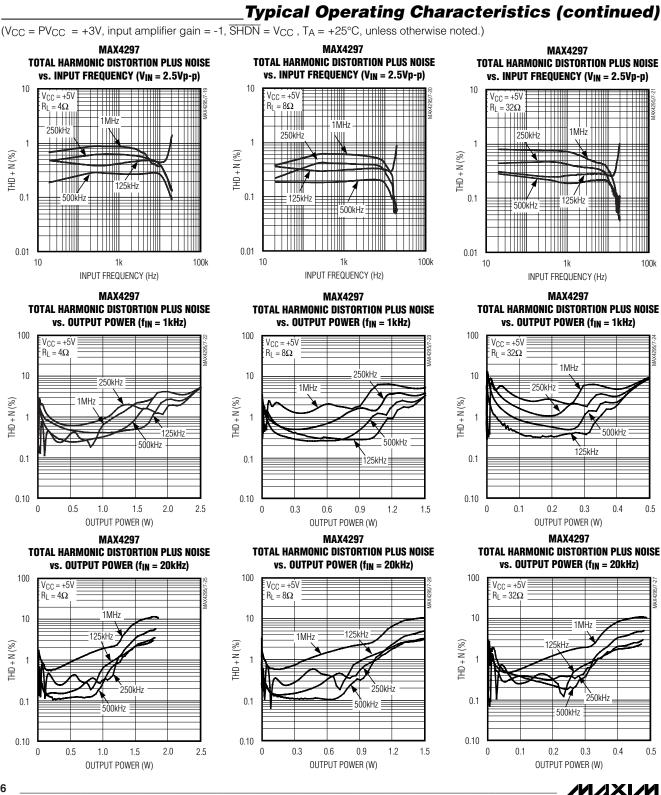
Note 1: All devices are 100% production tested at $T_A = 25^{\circ}C$. All temperature limits are guaranteed by design.

Note 2: Supply Voltage Range guaranteed by PSRR of input amplifier, frequency, duty cycle, and H-bridge on-resistance. **Note 3:** Guaranteed by design, not production tested.

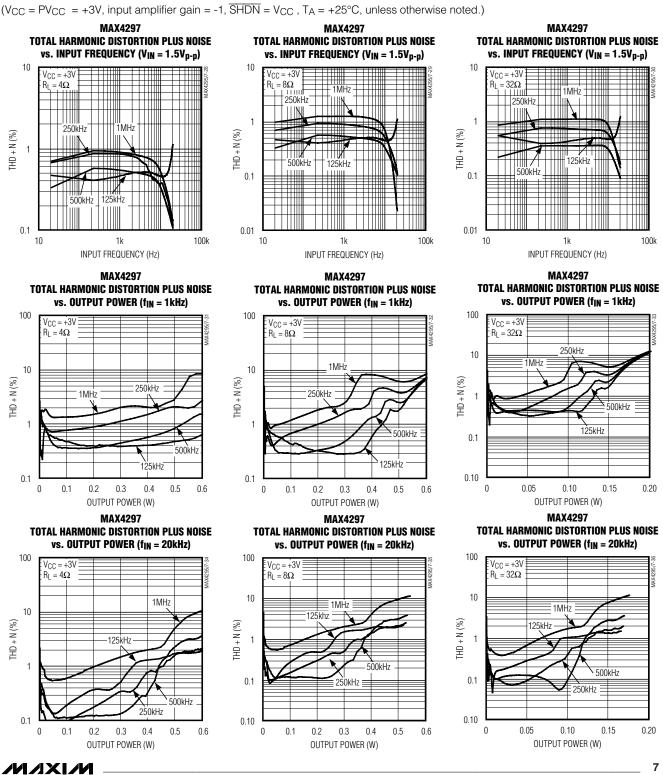


Typical Operating Characteristics (continued)





Typical Operating Characteristics (continued)



MAX4295/MAX4297

Typical Operating Characteristics (continued)

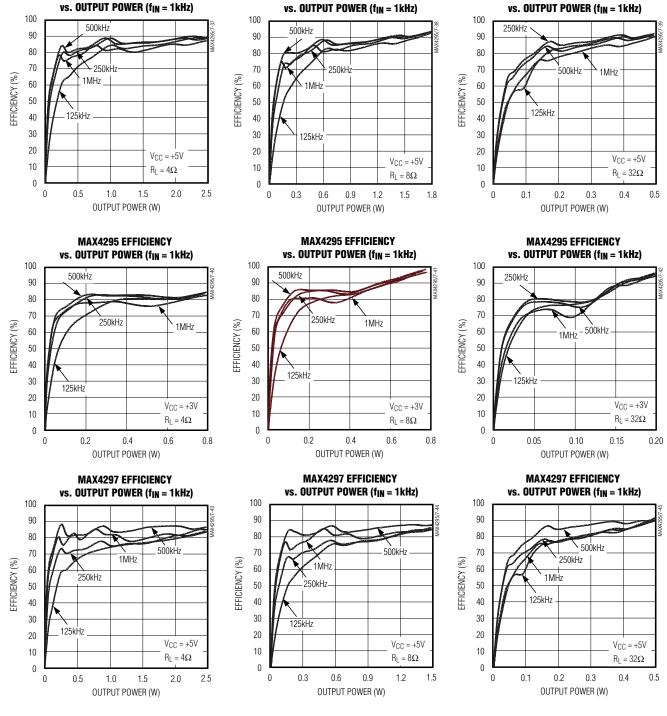
MAX4295 EFFICIENCY

(V_{CC} = PV_{CC} = +3V, input amplifier gain = -1, \overline{SHDN} = V_{CC}, T_A = +25°C, unless otherwise noted.)

100 90 80

MAX4295 EFFICIENCY

MAX4295/MAX4297

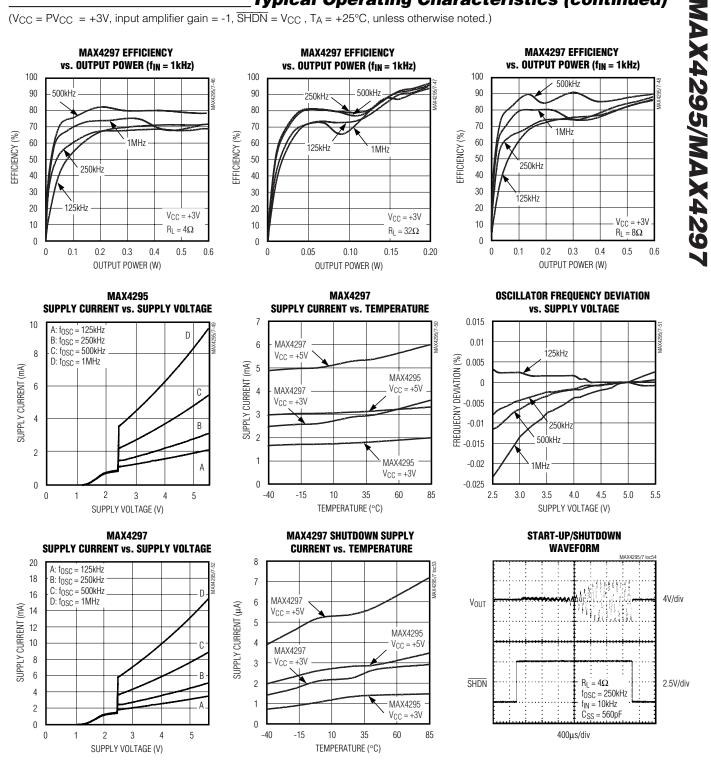


MAX4295 EFFICIENCY

M/IXI/N

Typical Operating Characteristics (continued)

 $(V_{CC} = PV_{CC} = +3V, \text{ input amplifier gain} = -1, \overline{SHDN} = V_{CC}, T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



/N/IXI/N

Pin Description

F	PIN	NAME	FUNCTION	
MAX4295	MAX4297	NAME	FUNCTION	
1, 12	10	GND	Analog Ground	
2, 15	4, 9, 16, 21	PVcc	H-Bridge Power Supply	
3	—	OUT+	Positive H-Bridge Output	
—	5	OUT+L	Positive Left-Channel H-Bridge Output	
—	8	OUT+R	Positive Right-Channel H-Bridge Output	
4, 13	6, 7, 18, 19	PGND	Power Ground	
5	3, 23	V _{CC}	Analog Power Supply	
6	13	VCM	Audio Input Common-Mode Voltage. Do not connect. Minimize parasitic coupling to this pin.	
7	_	IN	Audio Input	
	2	INL	Left-Channel Audio Input	
	11	INR	Right-Channel Audio Input	
8		AOUT	Input Amplifier Output	
	1	AOUTL	Left-Channel Input Amplifier Output	
	12	AOUTR	Right-Channel Input Amplifier Output	
9	22	SHDN	Active-Low Shutdown Input. Connect to V_{CC} for normal operation. Do not leave floating.	
10	14	FS1	Frequency Select Input 1	
11	15	FS2	Frequency Select Input 2	
14	_	OUT-	Negative H-Bridge Output	
_	20	OUT-L	Negative Left-Channel H-Bridge Output	
—	17	OUT-R	Negative Right-Channel H-Bridge Output	
16	24	SS	Soft-Start	

Detailed Description

The MAX4295/MAX4297 switch-mode, Class-D audio power amplifiers are intended for portable multimedia and general-purpose audio applications. Linear amplifiers in the 1W to 2W output range are inefficient; they overheat when operated near rated output power levels. The efficiency of linear amplifiers is <50% when the output voltage is equal to 1/2 the supply. The MAX4295/MAX4297 Class-D amplifiers achieve efficiencies of 87% or greater and are capable of delivering up to 2W of continuous maximum power to a 4 Ω load. The lost power is due mainly to the on-resistance of the power switches and ripple current in the output.

In a Class-D amplifier, a PWM controller converts the analog input to a variable pulse-width signal. The pulse width is proportional to the input voltage, ideally 0% for

a 0V input signal and 100% for full-scale input voltages. A passive lowpass LC network filters the PWM output waveform to reconstruct the analog signal. The switching frequency is selected much higher than the maximum input frequencies so that intermodulation products are outside the input signal bandwidth. Higher switching frequencies also simplify the filtering requirements.

The MAX4295/MAX4297 consist of an inverting input operational amplifier, a PWM ramp oscillator, a controller that converts the analog input to a variable pulse width signal, and a MOSFET H-bridge power stage (Figures 1a and 1b). The control signal is generated by the PWM comparator; its pulse width is proportional to the input voltage. Ideally the pulse width varies linearly between 0% for a 0V input signal and 100% for fullscale input voltages (Figure 2). This signal controls the

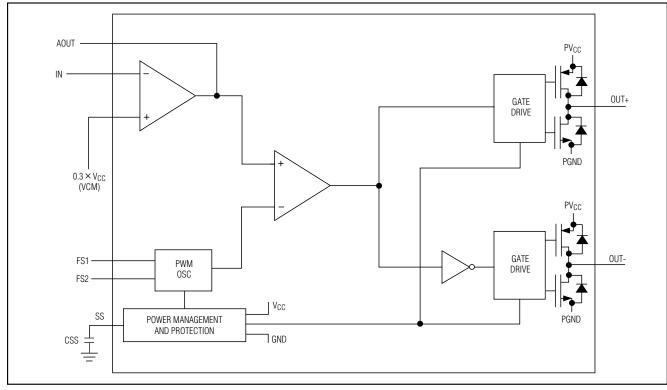


Figure 1a. MAX4295 Functional Diagram

H-bridge. The switches work in pairs to reverse the polarity of the signal in the load. Break-before-make switching of the H-bridge MOSFETs by the driver circuit keeps supply current glitches and crowbar current in the MOSFETs at a low level. The output swing of the Hbridge is a direct function of the supply voltage. Varying the oscillator swing in proportion to the supply voltage maintains constant gain with varying supply voltage.

FS1 and FS2 program the oscillator to a frequency of 125kHz, 250kHz, 500kHz, and 1MHz. The sawtooth oscillator swings between GND and 0.6 × V_{CC}. The input signal is typically AC-coupled to the internal input op amp, whose gain can be controlled through external feedback components. The common-mode voltage of the input amplifier is $0.3 \times V_{CC}$ and is internally generated from the same resistive divider used to generate the $0.6 \times V_{CC}$ reference for the PWM oscillator.

Current Limit

A current-limiting circuit in the H-bridge monitors the current in the H-bridge transistors and disables the Hbridge if the current in any of the H-bridge transistors exceeds 1A. The H-bridge is enabled after a period of $100 \mu s. \ A$ continuous short circuit at the output results in a pulsating output.

Thermal Overload Protection

Thermal overload protection limits total power dissipation in the MAX4295/MAX4297. When the junction temperature exceeds +145°C, the thermal detection disables the H-bridge transistors. The H-bridge transistors are enabled after the IC's junction temperature cools by 10°C. This results in a pulsating output under continuous thermal overload conditions. Junction temperature does not exceed the thermal overload trip point in normal operation, but only in the event of fault conditions, such as when the H-bridge outputs are short circuited.

Undervoltage Lockout

At low supply voltages, the MOSFETs in the H-bridge may have inadequate gate drive thus dissipating excessive power. The undervoltage lockout circuit prevents the device from operating at supply voltages below +2.2V.



MAX4295/MAX4297

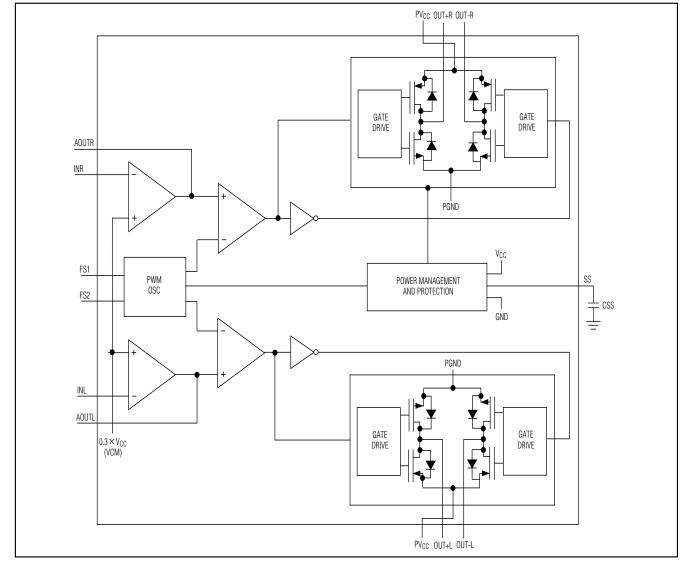


Figure 1b. MAX4297 Functional Diagram

Low-Power Shutdown Mode

The MAX4295/MAX4297 have a shutdown mode that reduces power consumption and extends battery life. Driving SHDN low disables the H-bridge, turns off the circuit, and places the MAX4295/MAX4297 in a low-power shutdown mode. Connect SHDN to V_{CC} for normal operation.

Applications Information

Component Selection

Gain Setting

External feedback components set the gain of the MAX4295/MAX4297. Resistors RF and RIN set the gain of the input amplifier to -(RF/RIN). The amplifier's noninverting input is connected to the internally generated $0.3 \times V_{CC}$ (VCM) that sets the amplifier's common-mode voltage.



The amplifier's input bias current is low, ±50pA, and does not affect the choice of feedback resistors. The noise in the circuit increases as the value of RF increases.

The optimum impedance seen by the inverting input is between 5k Ω and 20k Ω . The effective impedance is given by (RF × RIN)/(RF + RIN). For values of RF > 50k Ω , a small capacitor (~3pF) connected across RF compensates for the pole formed by the input capacitance and the effective resistance at the inverting input.

Soft-Start (Clickless Startup)

The H-bridge is disabled under any of the following conditions:

- SHDN low
- · H-bridge current exceeds the 1A current limit
- Thermal overload
- Undervoltage lockout

The circuit re-enters normal operation if none of the above conditions are present. A soft-start function prevents an audible pop on restart. An external capacitor connected to SS is charged by an internal 1.2 μ A current source and controls the soft-start rate. VSS is held low while the H-bridge is disabled and allowed to ramp up to begin a soft-start. Until VSS reaches 0.3 × VCC, the H-bridge output is limited to a 50% duty cycle, independent of the input voltage. The H-bridge duty cycle is then gradually allowed to track the input signal at a rate determined by the ramp on SS. The soft-start cycle is complete after VSS reaches 0.6 × VCC.

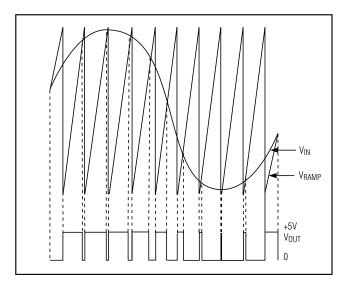


Figure 2. PWM Waveforms



Input Filter

High-fidelity audio applications require gain flatness between 20Hz to 20kHz. Set the low-frequency cutoff point with an AC-coupling capacitor in series with the input resistor of the amplifier, creating a highpass filter (Figure 3). Assuming the input node of the amplifier is a virtual ground, the -3dB point of the highpass filter is determined by: $f_{LO} = 1/(2\pi \times RIN \times CIN)$, where RIN is the input resistor, and CIN is the AC-coupling capacitor. Choose RIN as described in the *Gain Setting* section. Choose CIN such that the corner frequency is below 20Hz.

Frequency Selection

The MAX4295/MAX4297 have an internal logic-programmable oscillator controlled by FS1 and FS2 (Table 1). The oscillator can be programmed to frequencies of 125kHz, 250kHz, 500kHz, and 1MHz. The frequency should be chosen to best fit the application. As a rule of thumb, choose fOSC to be 10 times the audio bandwidth. A lower switching frequency offers higher amplifier efficiency and lower THD but requires larger external filter components. A higher switching frequency reduces the size and cost of the filter components at the expense of THD and efficiency. In most applications, the optimal fOSC is 250kHz.

Table 1. Frequency Select Logic

FS1	FS2	FREQUENCY (Hz)
0	0	125k
0	1	250k
1	0	500k
1	1	1M

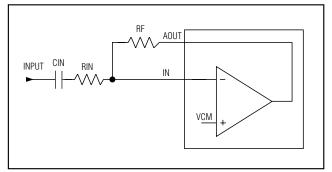


Figure 3. Input Amplifier Configuration

Output Filter

An output filter is required to attenuate the PWM switching frequency. Without the filter, the ripple in the load can substantially degrade efficiency and may cause interference problems with other electronic equipment.

A Butterworth lowpass filter is chosen for its flat pass band and nice phase response, though other filter implementations may also be used. Three examples are presented below. The filter parameters for balanced 2-pole (Figure 4b) and 4-pole (Figure 4d) Butterworth filters are taken from *Electronic Filter Design Handbook* by Arthur B. Williams, McGraw Hill, Inc. These filter designs assume that the load is purely resistive and load impedance is constant over frequency. Calculation of filter component values should include the DC resistance of the inductors and take into account the worst-case load scenario:

Single Ended 2-Pole Filter (Figure 4a)

$$C = 1 / (\sqrt{2} \times R_L \times \omega_0), L = \sqrt{2} \times R_L / \omega_0$$

where $\omega_0 = 2 \times \pi \times f_0$ (f_0 = filter cutoff frequency); choosing f_0 = 30kHz and R_L = 4 Ω , C = 0.937 μ F, L = 30 μ H.

A single-ended 2-pole filter uses the minimum number of external components, but the load (speaker) sees the large common-mode switching voltage, which can increase power dissipation and cause EMI problems.

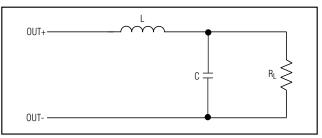


Figure 4a. Single-Ended 2-Pole Filter

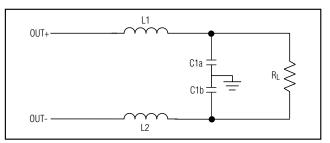


Figure 4b. Balanced 2-Pole Filter

Balanced 2-Pole (Figure 4b):

A balanced 2-Pole filter does not have the commonmode swing problem of the single-ended filter.

C = 2 / ($\sqrt{2} \times R_L \times \omega_0$), L = ($\sqrt{2} \times R_L$)/(2 × ω_0); choosing f₀ = 30kHz and R_L = 4 Ω , C1a = C1b = 2.0µF, L1a = L1b = 15µH.

A single capacitor connected across R_L, with a value of CL = $1/(\sqrt{2} \times R_L \times \omega_0)$, can be used in place of C1a and C1b. However, the configuration as shown gives an improved rejection to common-mode signal components of OUT+_ and OUT-_. If the single capacitor scheme is used, additional capacitors (Ca and Cb) can be added from each side of R_L, providing a high-frequency short to ground (Figure 4c). These capacitors should be approximately 0.2 × CL.

• Balanced 4-Pole Filter (Figure 4d)

A balanced 4-pole filter is more effective in suppressing the switching frequency and its harmonics.

For the 4-pole Butterworth filter, the normalized values are: $L1_N = 1.5307$, $L2_N = 1.0824$, $C1_N = 1.5772$, $C2_N = 0.3827$.

The actual inductance and capacitance values for $f_0 = 30$ kHz and a bridge-tied load of $R_L = 4\Omega$ are given by:

 $\begin{array}{l} L1 = \left(L1_N \times R_L\right) / \left(2 \times \omega_0\right) = 16.24 \mu H, \ L2 = \left(L2_N \times R_L\right) / \\ \left(2 \times \omega_0\right) = 11.5 \mu H, \ C1 = C1_N / \left(R_L \times \omega_0\right) = 2.1 \mu F, \ C2a = \\ C2b = \left(2 \times C2_N\right) / \left(R_L \times \omega_0\right) = 1.0 \mu F. \end{array}$

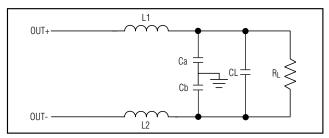


Figure 4c. Alternate Balanced 2-Pole Filter

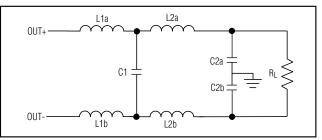


Figure 4d. Balanced 4-Pole Filter



Filter Components

The inductor current rating should be higher than the peak current for a given output power requirement and should have relatively constant inductance over temperature and frequency. Typically, an open-core inductor is desirable since these types of inductors are more linear. Toroidal inductors without an air gap are not recommended. Q-shielded inductors may be required if the amplifier is placed in an EMI-sensitive system. The series resistance of the inductors will reduce the attenuation of the switching frequency and reduce efficiency due to the ripple current in the inductor.

The capacitors should have a voltage rating 2 to 3 times the maximum expected RMS voltage—allowing for high peak voltages and transient spikes—and be stable over-temperature. Good quality capacitors with low equivalent series resistance (ESR) and equivalent series inductance (ESL) are necessary to achieve optimum performance. Low-ESR capacitors will decrease power dissipation. High ESL will shift the cutoff frequency, and high ESR will reduce filter rolloff.

Bridge-Tied Load/Single-Ended Configuration

The MAX4295/MAX4297 can be used as either a BTL or single-ended configured amplifier. The BTL configuration offers several advantages over a single-ended configuration. By driving the load differentially, the output voltage swing is doubled and the output power is quadrupled in comparison to a single-ended configura-

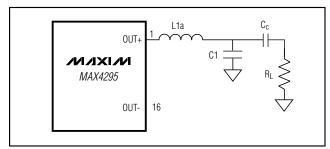


Figure 5. MAX4295 Single-Ended Configuration

tion. Because the differential outputs are biased at half supply, there is no DC voltage across the load, eliminating the need for large DC blocking capacitors at the output.

The MAX4295/MAX4297 can be configured as singleended amplifiers. In such a case, the load must be capacitively coupled to the filter to block the half-supply DC voltage from the load. The unused output pin

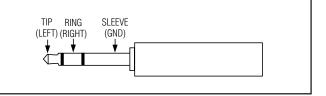


Figure 6. Typical 3-Wire Headphone Plug

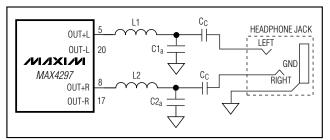


Figure 7. Headphone Application Circuit

must also be left open (Figure 5). Do not connect the unused output pin to ground.

Headphone Applications

MAX4295/MAX4297

The MAX4295/MAX4297 can be used to drive a set of headphones. A typical 3-wire headphone plug consists of a tip, ring, and sleeve. The tip and ring are signal carriers, while the sleeve is the ground connection (Figure 6). Figure 7 shows the MAX4297 configured to drive a set of headphones. The OUT+L and OUT+R pins are connected to the tip and ring and deliver the signal to the headphone jack, while the OUT-L and OUT-R pins remain unconnected. The ground connection in the jack should be connected to the same ground plane as the output filter.

Total Harmonic Distortion

The MAX4295/MAX4297 exhibit typical THD plus noise of <1% for input frequencies <10kHz. The PWM frequency affects THD performance. THD can be reduced by limiting the input bandwidth through the input highpass filter, choosing the lowest f_{OSC} possible, and carefully selecting the output filter and its components.

Bypassing and Layout Considerations

Distortion caused by supply ripple due to H-bridge switching can be reduced through proper bypassing of PV_{CC}. For optimal performance, a 330 μ F, low-ESR POSCAP capacitor to PGND and a 1 μ F ceramic capacitor to GND at each PV_{CC} input is suggested. Place the 1 μ F capacitor close to the PV_{CC} pin. Bypass V_{CC} with



a 10 μF capacitor in parallel with a 1 μF capacitor to GND. Ceramic capacitors are recommended due to their low ESR.

Good PC board layout techniques optimize performance by decreasing the amount of stray capacitance at the amplifier's inputs and outputs. To decrease stray capacitance, minimize trace lengths by placing external components as close as possible to the amplifier. Surface-mount components are recommended.

The MAX4295/MAX4297 require two separate ground planes to prevent switching noise from the MOSFETs in the H-bridge from coupling into the rest of the circuit. PGND, the power ground, is utilized by the H-bridge and any external output components, while GND is used by the rest of the circuit. Connect the PGND and GND planes at only one point, as close to the power supply as possible. Any external components associated with the output of the MAX4295/MAX4297 must be connected to the PGND plane where applicable. Use the *Typical Operating Circuit* diagram as a reference.

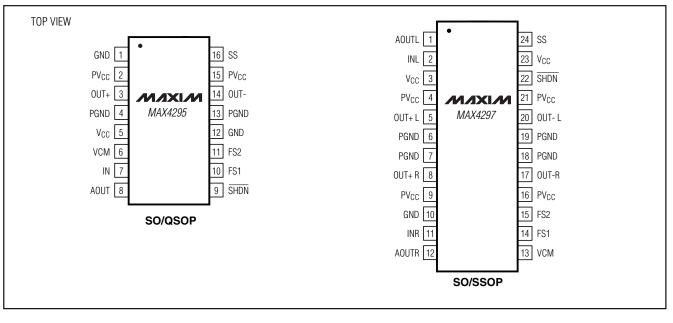
Refer to the evaluation kit manual for suggested component values, component suppliers, and layout.

Chip Information

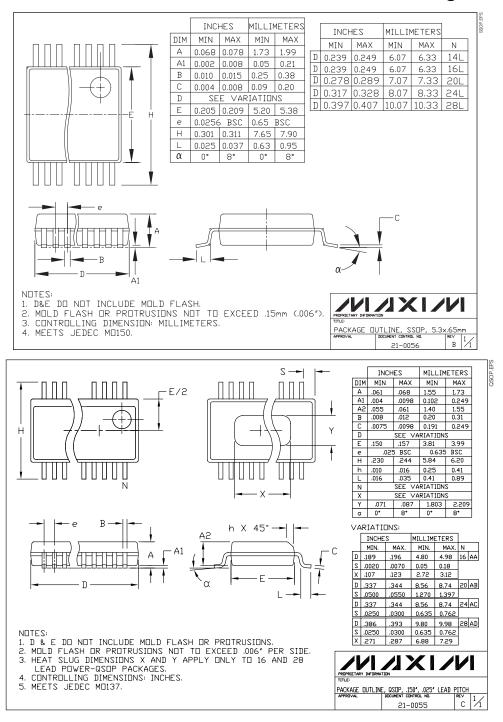
TRANSISTOR COUNT: MAX4295: 846 MAX4297: 1191

PROCESS: BiCMOS

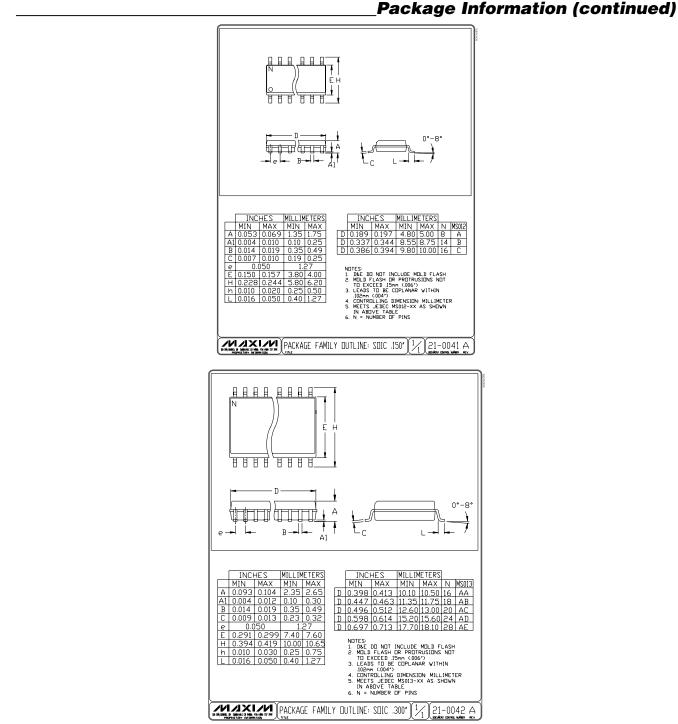
Pin Configurations



Package Information



MAX4295/MAX4297



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

____Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600

© 2001 Maxim Integrated Products

18

Printed USA

is a registered trademark of Maxim Integrated Products.